

FEATURES

- Low offset voltage and offset current
- Low offset voltage and current drift
- Low input bias current
- Low input noise voltage
- Large common mode and differential voltage ranges

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	$\pm 22V$
Internal Power Dissipation (Note 1)	
Metal Can	500mW
Differential Input Voltage	$\pm 30V$
Input Voltage (Note 2)	$\pm 15V$
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$
Operating Temperature Range (HC)	$0^{\circ}C$ to $70^{\circ}C$
(HM)	$-55^{\circ}C$ to $+125^{\circ}C$
Lead Temperature (Soldering, 10s)	$300^{\circ}C$
	$260^{\circ}C$
Output Short Circuit Duration (Note 3)	Indefinite

Note 1: Rating applies to ambient temperatures up to $70^{\circ}C$. Above $70^{\circ}C$ ambient derate linearly at $6.3mW/^{\circ}C$ for Metal Can, $8.3mW/^{\circ}C$ for the DIP, and $5.6mW/^{\circ}C$ for the Mini DIP.

Note 2: For supply voltages less than $\pm 15V$, the absolute maximum input voltage is equal to the supply voltage.

Note 3: Short Circuit may be to ground or either supply. Rating applies to $+125^{\circ}C$ case temperature or $+75^{\circ}C$ ambient temperature for $I_{SET} \leq 30\mu A$.

ORDERING INFORMATION

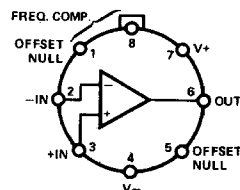
	Dice	TO-99 Can
$\mu A777C$	$\mu A777C/D$	$\mu A777HC$
$\mu A777M$	$\mu A777M/D$	$\mu A777MC$

GENERAL DESCRIPTION

The $\mu A777$ is a monolithic Precision Operational Amplifier. It is an excellent choice when performance versus cost trade-offs are possible between super beta or FET input operational amplifiers and low cost general purpose operational amplifiers. Low offset and bias currents improve system accuracy when used in applications such as long term integrators, sample and hold circuits and high source impedance summing amplifiers. Even though the input bias current is extremely low, the $\mu A777$ maintains full $\pm 30V$ differential voltage range. High common mode input voltage range, latch-up protection, short circuit protection and simple frequency compensation make the device versatile and easily used.

PIN CONFIGURATION

**8-LEAD METAL CAN
(TOP VIEW)**

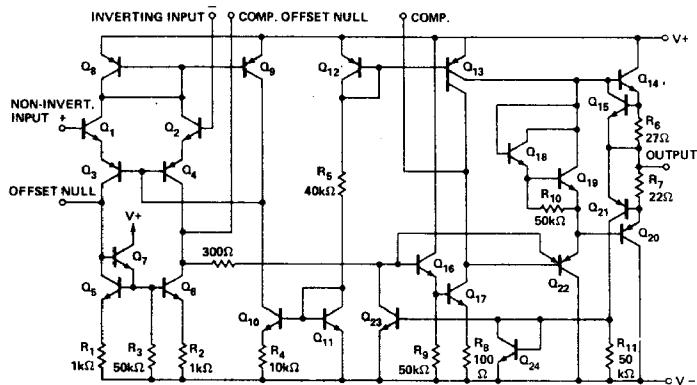


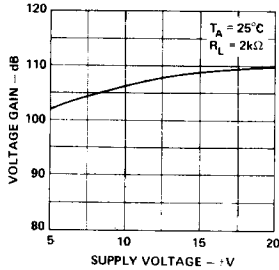
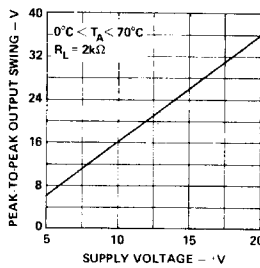
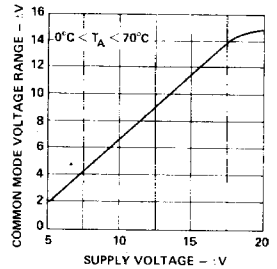
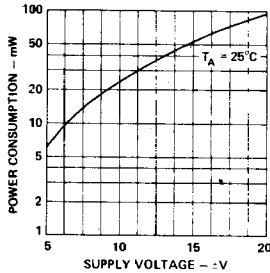
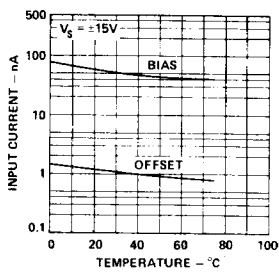
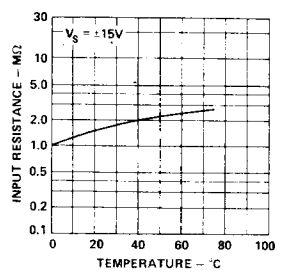
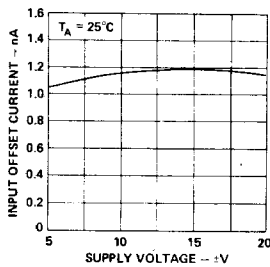
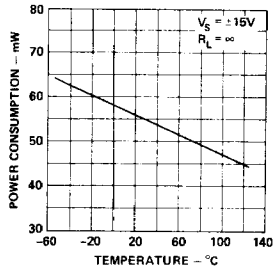
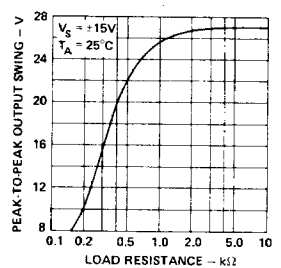
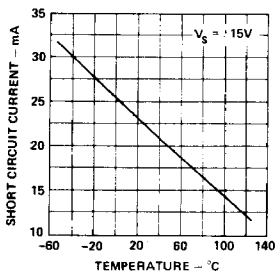
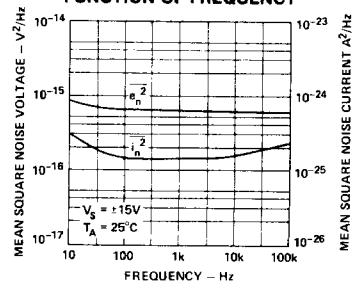
(outline dwg TY)

ELECTRICAL CHARACTERISTICS FOR μA777 ($V_S = \pm 15V$, $T_A = 25^\circ C$, $C_C = 30pF$ unless otherwise specified)

PARAMETERS		CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage		$R_S \leq 50k\Omega$		0.7	5.0	mV
Input Offset Current				0.7	20.0	nA
Input Bias Current				25	100	nA
Input Resistance			1.0	2.0		MΩ
Input Capacitance				3.0		pF
Offset Voltage Adjustment Range				±25		mV
Large Signal Voltage Gain		$R_L \geq 2k\Omega$, $V_{OUT} = \pm 10V$	25,000	250,000		V/V
Output Resistance				100		Ω
Output Short Circuit Current				±25		mA
Supply Current				1.9	2.8	mA
Power Consumption				60	85	mW
Transient Response (Voltage Follower, Gain of 1)	Rise Time	$V_{IN} = 20mV$, $C_C = 30pF$ $R_L = 2k\Omega$, $C_L \leq 100pF$		0.3		μs
	Overshoot			5.0		%
Slew Rate (Voltage Follower, Gain of 1)		$R_L \geq 2k\Omega$		0.5		V/μs
Transient Response (Voltage Follower, Gain of 10)	Rise Time	$V_{IN} = 20mV$, $C_C = 3.5pF$ $R_L = 2k\Omega$, $C_L \leq 100pF$		0.3		μs
	Overshoot			5.0		%
Slew Rate (Voltage Follower, Gain of 10)		$R_L \leq 2k\Omega$, $C_C = 3.5pF$		5.5		V/μs
The following specifications apply over operating temperature range.						
Input Offset Voltage		$R_S \leq 50k\Omega$		0.8	5.0	mV
Average Input Offset Voltage Drift		$R_S \leq 50k\Omega$		4.0	30	μV/°C
Input Offset Current					40	nA
Average Input Offset Current Drift		$25^\circ C \leq T_A \leq +70^\circ C$ $0^\circ C \leq T_A \leq +25^\circ C$		0.01 0.02	10.3 0.6	nA/°C
Input Bias Current					200	nA
Input Voltage Range			±12	±13		V
Common Mode Rejection Ratio		$R_S \leq 50k\Omega$	70	95		dB
Supply Voltage Rejection Ratio		$R_S \leq 50k\Omega$		15	150	μV/V
Large Signal Voltage Gain		$R_L \geq 2k\Omega$, $V_{OUT} = \pm 10V$	15,000			V/V
Output Voltage Swing		$R_L \geq 10k\Omega$	±12	±14		V
		$R_L \geq 2k\Omega$	±10	±13		V
Power Consumption				60	100	mW

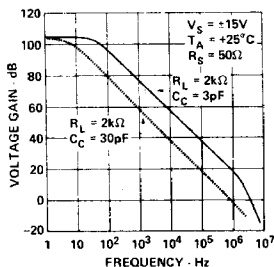
EQUIVALENT CIRCUIT



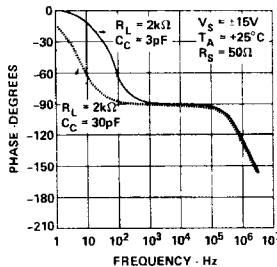
TYPICAL PERFORMANCE CURVES**OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF SUPPLY VOLTAGE****OUTPUT VOLTAGE SWING AS A FUNCTION OF SUPPLY VOLTAGE****INPUT COMMON MODE VOLTAGE RANGE AS A FUNCTION OF SUPPLY VOLTAGE****POWER CONSUMPTION AS A FUNCTION OF SUPPLY VOLTAGE****INPUT CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE****INPUT RESISTANCE AS A FUNCTION OF AMBIENT TEMPERATURE****INPUT OFFSET CURRENT AS A FUNCTION OF SUPPLY VOLTAGE****POWER CONSUMPTION AS A FUNCTION OF AMBIENT TEMPERATURE****OUTPUT VOLTAGE SWING AS A FUNCTION OF LOAD RESISTANCE****OUTPUT SHORT-CIRCUIT CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE****INPUT NOISE VOLTAGE AND CURRENT AS A FUNCTION OF FREQUENCY**

TYPICAL PERFORMANCE CURVES

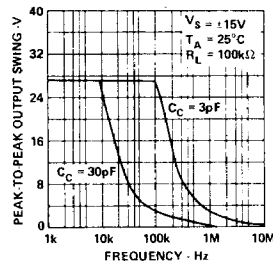
**OPEN LOOP VOLTAGE GAIN
AS A FUNCTION OF
FREQUENCY**



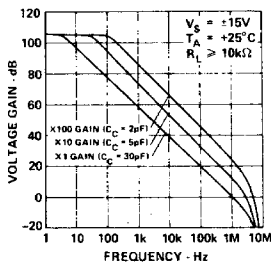
**OPEN LOOP PHASE
RESPONSE AS A
FUNCTION OF FREQUENCY**



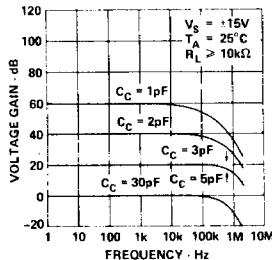
**OUTPUT VOLTAGE SWING
AS A FUNCTION OF
FREQUENCY**



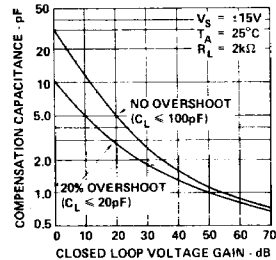
**OPEN LOOP VOLTAGE GAIN
AS A FUNCTION OF
FREQUENCY FOR VARIOUS
GAIN/COMPENSATION OPTIONS**



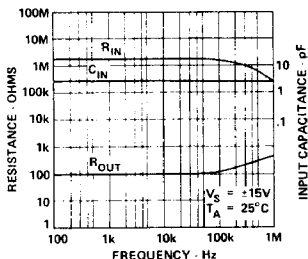
**FREQUENCY RESPONSE
FOR VARIOUS
CLOSED-LOOP GAINS**



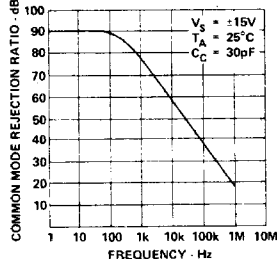
**COMPENSATION
CAPACITANCE AS A
FUNCTION OF CLOSED
LOOP VOLTAGE GAIN**



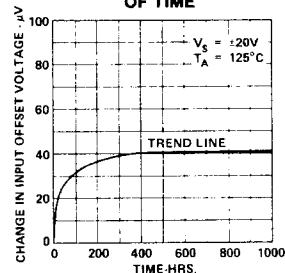
**INPUT RESISTANCE,
OUTPUT RESISTANCE,
AND INPUT CAPACITANCE
AS A FUNCTION OF FREQUENCY**



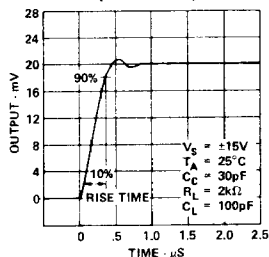
**COMMON MODE REJECTION
RATIO AS A FUNCTION OF
FREQUENCY**



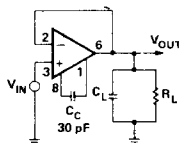
**INPUT OFFSET VOLTAGE
DRIFT AS A FUNCTION
OF TIME**



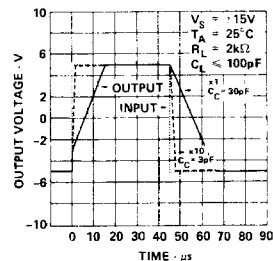
**VOLTAGE FOLLOWER
TRANSIENT RESPONSE
(GAIN OF 1)**



**TRANSIENT RESPONSE
TEST CIRCUIT**

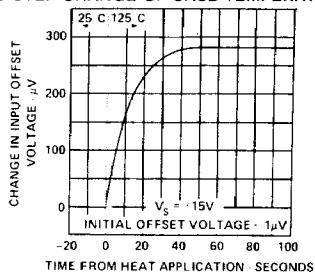


**VOLTAGE FOLLOWER
LARGE SIGNAL
PULSE RESPONSE**

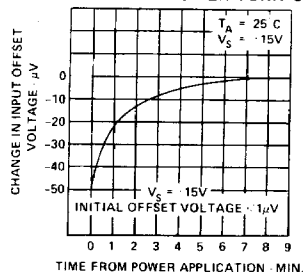


TYPICAL PERFORMANCE CURVES

THERMAL RESPONSE OF INPUT OFFSET VOLTAGE TO STEP CHANGE OF CASE TEMPERATURE

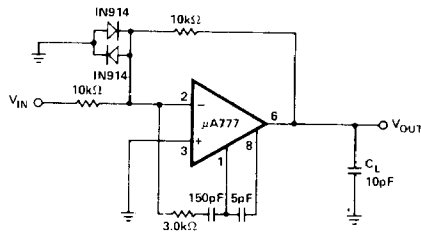
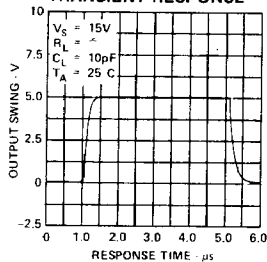


STABILIZATION TIME OF INPUT OFF-SET VOLTAGE FROM POWER TURN-ON

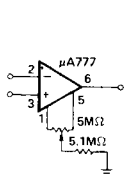


FEED FORWARD COMPENSATION

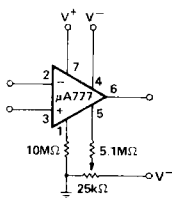
LARGE SIGNAL FEEDFORWARD TRANSIENT RESPONSE



VOLTAGE OFFSET NULL CIRCUIT

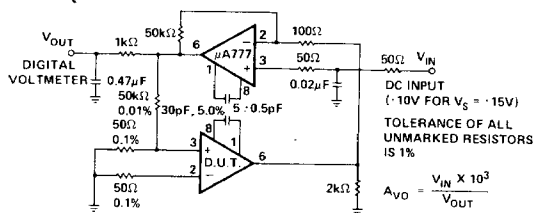


SUGGESTED



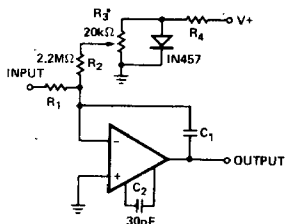
ALTERNATE

GAIN TEST CIRCUIT



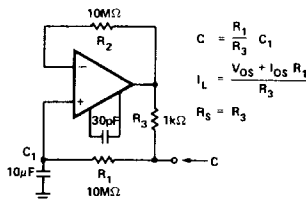
TYPICAL APPLICATIONS

BIAS COMPENSATED LONG TIME INTEGRATOR

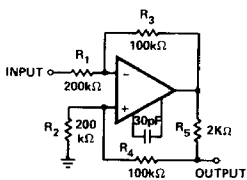


*ADJUST R_3 FOR MINIMUM INTEGRATOR DRIFT

CAPACITANCE MULTIPLIER

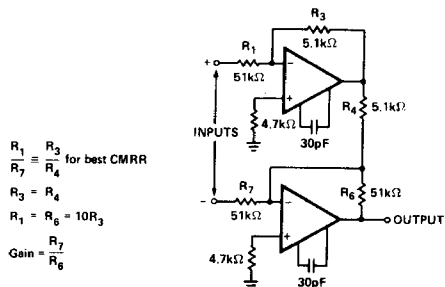


BILATERAL CURRENT SOURCE

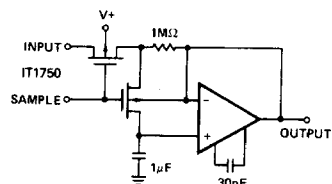


$$I_{OUT} = \frac{R_3 V_{IN}}{R_1 R_5} \quad R_1 = R_2; R_3 = R_4 + R_5$$

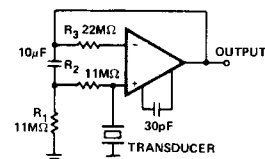
±100V COMMON MODE RANGE INSTRUMENTATION AMPLIFIER



SAMPLE AND HOLD

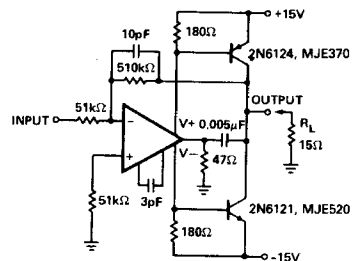


AMPLIFIER FOR CAPACITANCE TRANSDUCERS

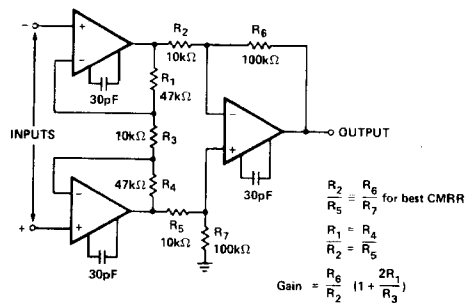


LOW FREQUENCY CUTOFF $R_1 \times C_1$

HIGH SLEW RATE POWER AMPLIFIER



INSTRUMENTATION AMPLIFIER WITH HIGH COMMON MODE REJECTION





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Благодаря этому наша компания предлагает к поставке практически не ограниченный ассортимент компонентов как оптовыми, мелкооптовыми партиями, так и в розницу.

Благодаря развитой сети поставщиков, помогаем в поиске и приобретении экзотичных или снятых с производства компонентов.

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